

Switching Diode

FUTURE

- We declare that the material of product compliance with RoHS requirements.

Ordering Information

Device	Marking	Shipping
LMBD6050LT1G	5A	3000/Tape&Reel
LMBD6050LT3G	5A	10000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	70	Vdc
Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{F(\text{surge})}$	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾	P _D	225	mW
T _A = 25°C			
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	556	°C/W
Total Device Dissipation	P _D	300	mW
Alumina Substrate, ⁽²⁾ T _A = 25°C			
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

DEVICE MARKING

LMBD6050LT1 G= 5A

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

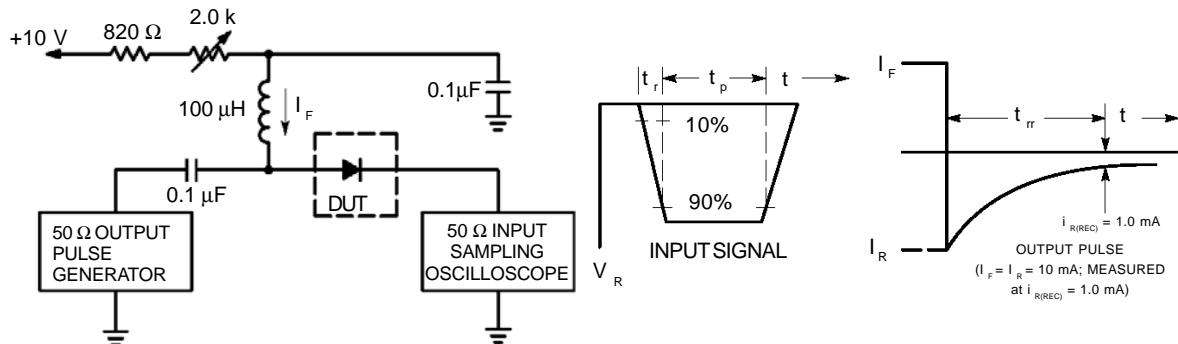
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage ($I_{(BR)} = 100 \mu\text{A}\text{dc}$)	$V_{(\text{BR})}$	70	—	Vdc
Reverse Voltage Leakage Current ($V_R = 50 \text{ Vdc}$)	I_R	—	0.1	$\mu\text{A}\text{dc}$
Forward Voltage ($I_F = 1.0 \text{ mA}\text{dc}$) ($I_F = 100 \text{ mA}\text{dc}$)	V_F			Vdc
Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}\text{dc}, I_{(REC)} = 1.0 \text{ mA}\text{dc}$) (Figure 1)	t_{rr}	—	4.0	ns
Capacitance($V_R = 0 \text{ V}$)	C	—	2.5	pF

$$1. \text{ FR-5} = 1.0 \times 0.75 \times 0.062 \text{ in.}$$

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

1/3

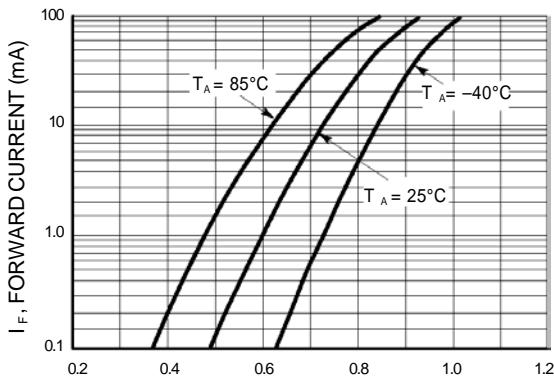
LMBD6050LT1G



- Notes:
1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10mA.
 2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10mA.
 3. $t_p \gg t_{rr}$

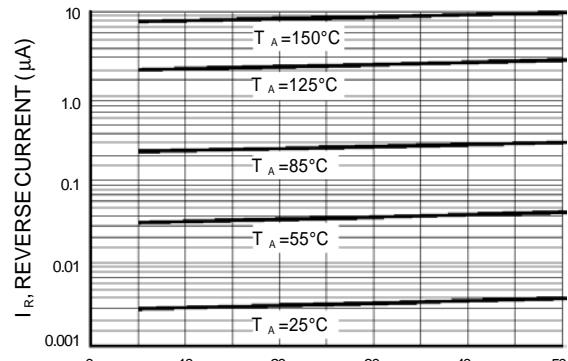
Figure 1. Recovery Time Equivalent Test Circuit

TYPICAL CHARACTERISTICS



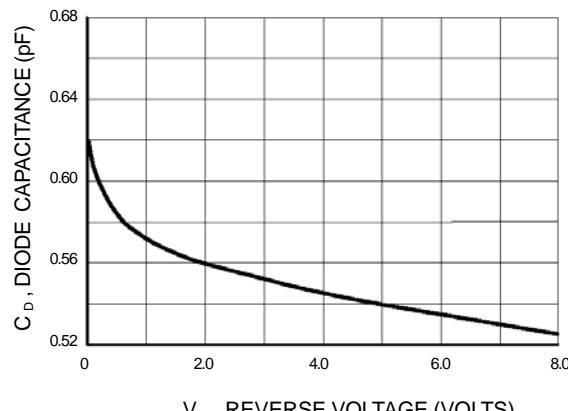
V_F , FORWARD VOLTAGE (VOLTS)

Figure 2. Forward Voltage



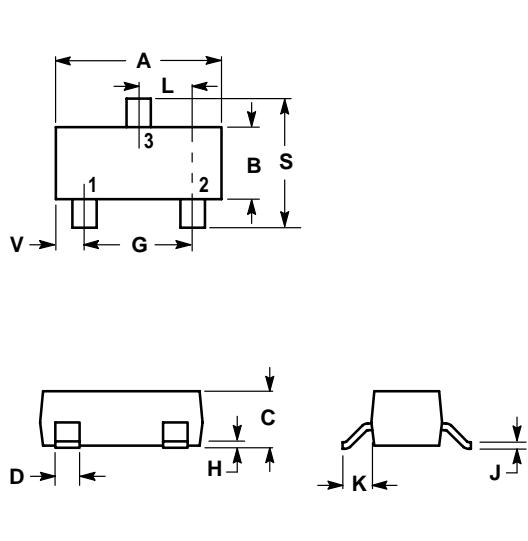
V_R , REVERSE VOLTAGE (VOLTS)

Figure 3. Leakage Current



V_R , REVERSE VOLTAGE (VOLTS)

Figure 4. Capacitance

LMBD6050LT1G
SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

